



DMT6016LPS

60V N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI®

### **Product Summary**

V <sub>(BR)DSS</sub>	Rds(on)	Ι <sub>D</sub> T <sub>C</sub> = +25°C
60V	15mΩ @ V <sub>GS</sub> = 10V	32 A
00 V	24mΩ @ V <sub>GS</sub> = 4.5V	24 A

### Description

This MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

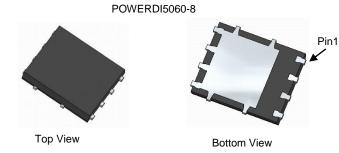
- Load Switch
- Adaptor Switch
- Notebook PC

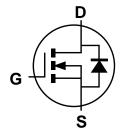
#### Features

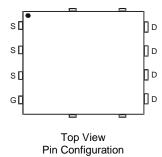
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low <sub>RDS(ON)</sub> Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

# **Mechanical Data**

- Case: POWERDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Weight: 0.097 grams (Approximate)







Internal Schematic

## Ordering Information (Note 4)

Part Number	Case	Packaging
DMT6016LPS-13	POWERDI5060-8	2,500 / Tape & Reel

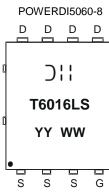
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



 $)''_{+} = Manufacturer's Marking$ T6016LS = Product Type Marking CodeYYWW = Date Code MarkingYY = Last Digit of Year (ex: 14 = 2014)WW = Week Code (01 to 53)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V <sub>DSS</sub>	60	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$	I <sub>D</sub>	32 25	А
Continuous Drain Current (Note 6) $V_{GS} = 10V$	t < 10s	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	Ι <sub>D</sub>	14.8 11.9	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I <sub>DM</sub>	60	A
Maximum Continuous Body Diode Forward Current (Note 6)			I <sub>S</sub>	2	А
Avalanche Current (Note 8) L = 0.1mH			I <sub>AS</sub>	15.3	А
Avalanche Energy (Note 8) L = 0.1mH			E <sub>AS</sub>	11.7	mJ

## **Thermal Characteristics**

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)		PD	1.23	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	P	102	°C/W
memai Resistance, Junction to Ambient (Note 5)	t<10s	$R_{ extsf{ heta}JA}$	52	
Total Power Dissipation (Note 6)		PD	2.7	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	P	49	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{ extsf{ heta}JA}$	24	
Thermal Resistance, Junction to Case (Note 7)		$R_{\theta JC}$	4.8	°C/W
Operating and Storage Temperature Range		T <sub>J.</sub> T <sub>STG</sub>	-55 to +150	°C

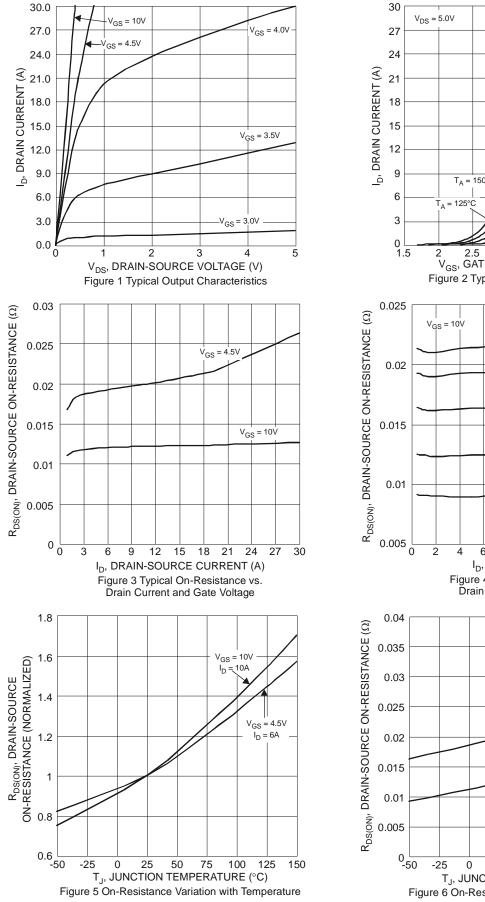
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

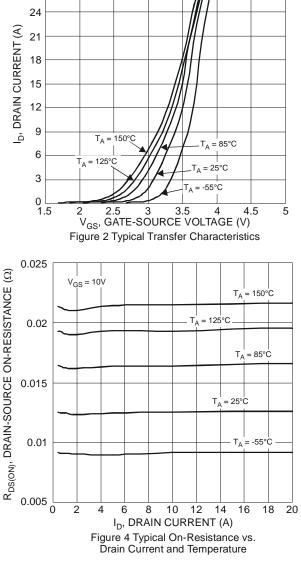
r						-	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)					-	-	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μA	$V_{DS}$ =48V, $V_{GS}$ = 0V	
Gate-Source Leakage	IGSS		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	1	—	2.5	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		_	—	15	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R <sub>DS (ON)</sub>		—	24	11152	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 18A	
Diode Forward Voltage	V <sub>SD</sub>		0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C <sub>iss</sub>	_	864	—			
Output Capacitance	Coss		282	_	pF	$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>		27	—			
Gate Resistance	R <sub>G</sub>	—	1.3	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	—	8.4	_			
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	—	17	_	nC	Vps = 30V. lp = 10A	
Gate-Source Charge	Q <sub>gs</sub>	—	3.1	_	ne	$v_{DS} = 30v, I_D = 10A$	
Gate-Drain Charge	Q <sub>gd</sub>	—	4.3	_			
Turn-On Delay Time	t <sub>D(on)</sub>	_	3.4	—			
Turn-On Rise Time	tr	_	5.2	_		$\label{eq:VGS} \begin{array}{l} V_{\mathrm{GS}} = 10V, \ V_{\mathrm{DS}} = 30V, \\ R_{\mathrm{G}} = 6\Omega, \ I_{\mathrm{D}} = 10A \end{array}$	
Turn-Off Delay Time	t <sub>D(off)</sub>	_	13	_	ns		
Turn-Off Fall Time	tf	_	7	_			
Reverse Recovery Time	t <sub>rr</sub>	_	22	_	ns	1 100 di/dt 1000/us	
Reverse Recovery Charge	Qrr	_	11	—	nC	I <sub>F</sub> = 10A, di/dt = 100A/μs	

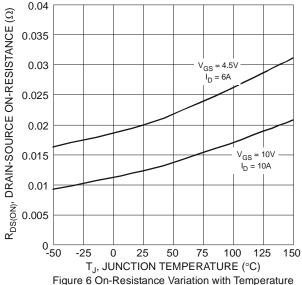
Notes:

Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).
I<sub>AS</sub> and E<sub>AS</sub> rating are based on low frequency and duty cycles to keep T<sub>J</sub> = +25°C.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

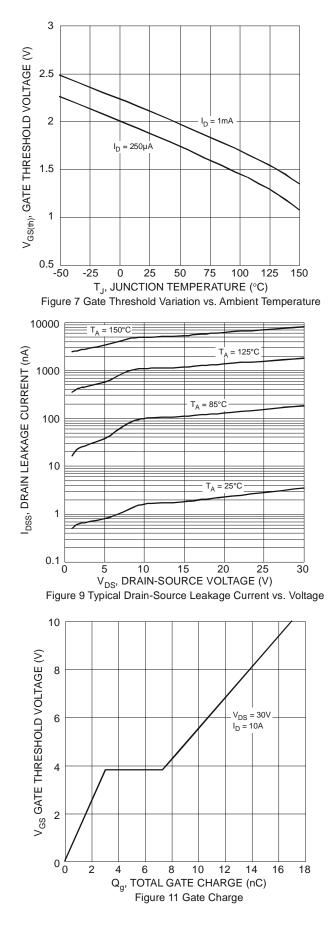


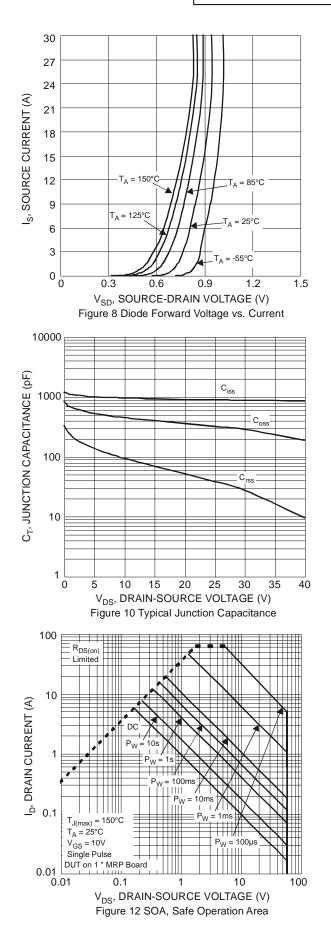






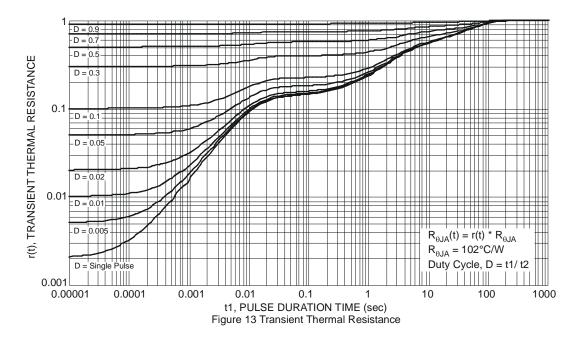






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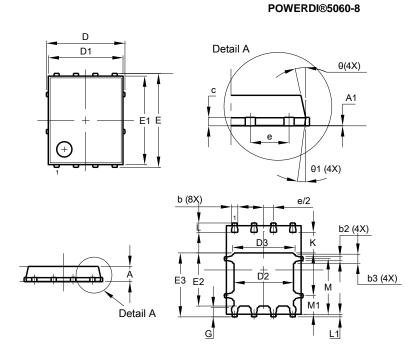






# **Package Outline Dimensions**

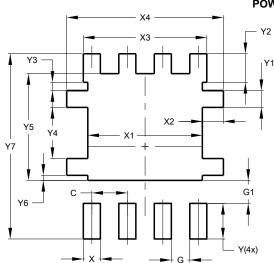
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



POWERDI®5060-8							
Dim	Min	Max	Тур				
Α	0.90	1.10	1.00				
A1	0.00	0.05					
b	0.33	0.51	0.41				
b2	0.200	0.350	0.273				
b3	0.40	0.80	0.60				
С	0.230	0.330	0.277				
D		5.15 BSC	;				
D1	4.70	5.10	4.90				
D2	3.70	4.10	3.90				
D3	3.90	4.30	4.10				
E	(	6.15 BSC					
E1	5.60	6.00	5.80				
E2	3.28	3.68	3.48				
E3	3.99	4.39	4.19				
е		1.27 BSC	;				
G	0.51	0.71	0.61				
K	0.51						
L	0.51	0.71	0.61				
L1	0.100	0.200	0.175				
М	3.235	4.035	3.635				
M1	1.00	1.40	1.21				
Θ	10°	12º	11º				
Θ1	6°	8°	7°				
AI	l Dimens	ions in m	nm				

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



#### POWERDI<sup>®</sup>5060-8

Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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